# Onsemi

# **MOSFET** – Power, **Dual N-Channel, for 1-2 Cells Lithium-ion Battery Protection**

# 24 V, 45 mΩ, 6 A

# **EFC4612R-S**

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-2 cells lithium-ion battery applications.

#### Features

- 2.5 V Drive
- Common–Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halide Free and RoHS Compliant

#### Applications

• 1–2 Cells Lithium–ion Battery Charging and Discharging Switch

#### SPECIFICATIONS

#### ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub> = 25°C

Parameter	Symbol	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>	24	V
Gate to Source Voltage	V <sub>GSS</sub>	±12	V
Source Current (DC)	۱ <sub>S</sub>	6	А
Source Current (Pulse) PW $\leq$ 10 $\mu$ s, duty cycle $\leq$ 1%	I <sub>SP</sub>	60	A
Total Dissipation (Note 2)	PT	1.6	W
Junction Temperature	Tj	°C	
Storage Temperature	Tstg	–55 to +150	°C

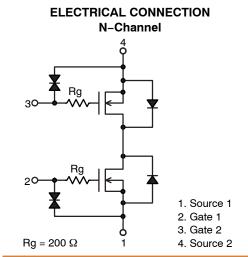
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

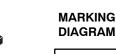
#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\theta JA}$	78.1	°C/W

1. Surface mounted on ceramic substrate (5000 mm<sup>2</sup>  $\times$  0.8 mm).

V <sub>SSS</sub>	R <sub>SS(on)</sub> Max	I <sub>S</sub> Max
24 V	45 mΩ @ 4.5 V	6 A
	48 mΩ @ 4.0 V	
	$50~\text{m}\Omega$ @ $3.7~\text{V}$	
	$57 \text{ m}\Omega @ 3.1 \text{ V}$	
	72 mΩ @ 2.5 V	





# DIAGRAM

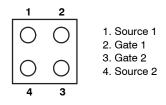
WLCSP4, 1.3 × 1.3 / EFCP1313-4CC-037 CASE 567DP

	FNY MZZ	
0		

FN = Specific Device Code

- Υ = Year
- М = Month
- ZZ = Assembly Lot Number

#### **PIN CONNECTIONS**



#### **ORDERING INFORMATION**

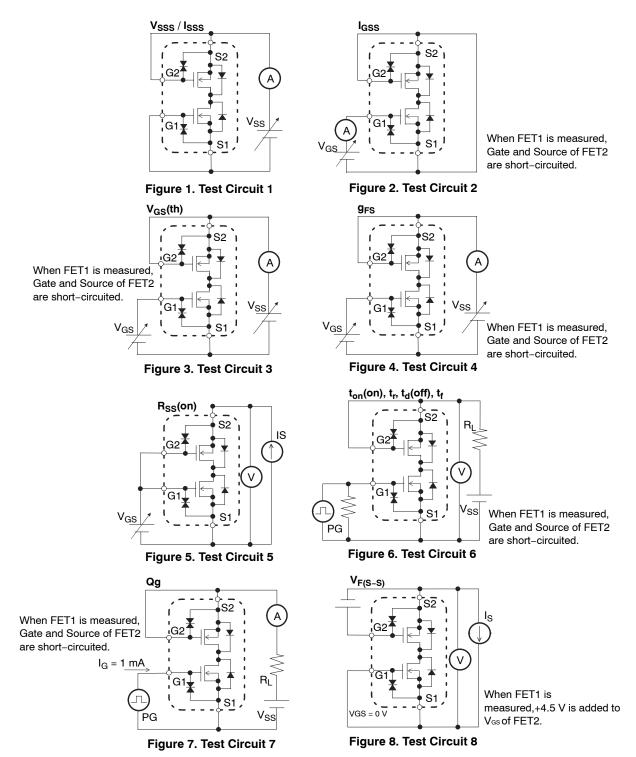
See detailed ordering and shipping information on page 6 of this data sheet.

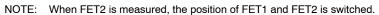
### **ELECTRICAL CHARACTERISTICS** at $T_A = 25^{\circ}C$

				Value			
Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I <sub>S</sub> = 1 mA, V <sub>GS</sub> = 0 V	(Figure 1)	24	-	_	V
Zero-Gate Voltage Source Current	I <sub>SSS</sub>	$V_{SS}$ = 20 V, $V_{GS}$ = 0 V	(Figure 1)	-	-	1	μΑ
Gate to Source Leakage Current	I <sub>GSS</sub>	$V_{GS}$ = ±8 V, $V_{SS}$ = 0 V	(Figure 2)	-	-	±10	μA
Gate Threshold Voltage	V <sub>GS</sub> (th)	$V_{SS} = 10 \text{ V}, \text{ I}_{S} = 1 \text{ mA}$	(Figure 3)	0.5	-	1.3	V
Forward Transconductance	9 <sub>FS</sub>	$V_{SS} = 10 \text{ V}, \text{ I}_{S} = 3 \text{ A}$	(Figure 4)	-	3.1	_	S
Static Source to Source On-State Resistance	R <sub>SS</sub> (on)1	$V_{GS}$ = 4.5 V, I <sub>S</sub> = 3 A	(Figure 5)	24	39	45	mΩ
	R <sub>SS</sub> (on)2	$V_{GS}$ = 4.0 V, I <sub>S</sub> = 3 A	(Figure 5)	25	41	48	mΩ
	R <sub>SS</sub> (on)3	$V_{GS}$ = 3.7 V, I <sub>S</sub> = 3 A	(Figure 5)	27.5	43	50	mΩ
	R <sub>SS</sub> (on)4	$V_{GS} = 3.1 \text{ V}, I_S = 3 \text{ A}$	(Figure 5)	31.5	48	57	mΩ
	R <sub>SS</sub> (on)5	$V_{GS}$ = 2.5 V, I <sub>S</sub> = 3 A	(Figure 5)	33.5	58	72	mΩ
Turn-ON Delay Time	t <sub>d</sub> (on)	$V_{SS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V},$	(Figure 6)	-	20	-	ns
Rise Time	t <sub>r</sub>	I <sub>S</sub> = 3 A		-	230	-	ns
Turn-OFF Delay Time	t <sub>d</sub> (off)			-	130	-	ns
Fall Time	t <sub>f</sub>	1		-	210	_	ns
Total Gate Charge	Qg	$V_{SS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{S}$ = 6 A	(Figure 7)	-	7	-	nC
Forward Source to Source Voltage	V <sub>F(S-S)</sub>	I <sub>S</sub> = 3 A, V <sub>GS</sub> = 0 V	(Figure 8)	-	0.8	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

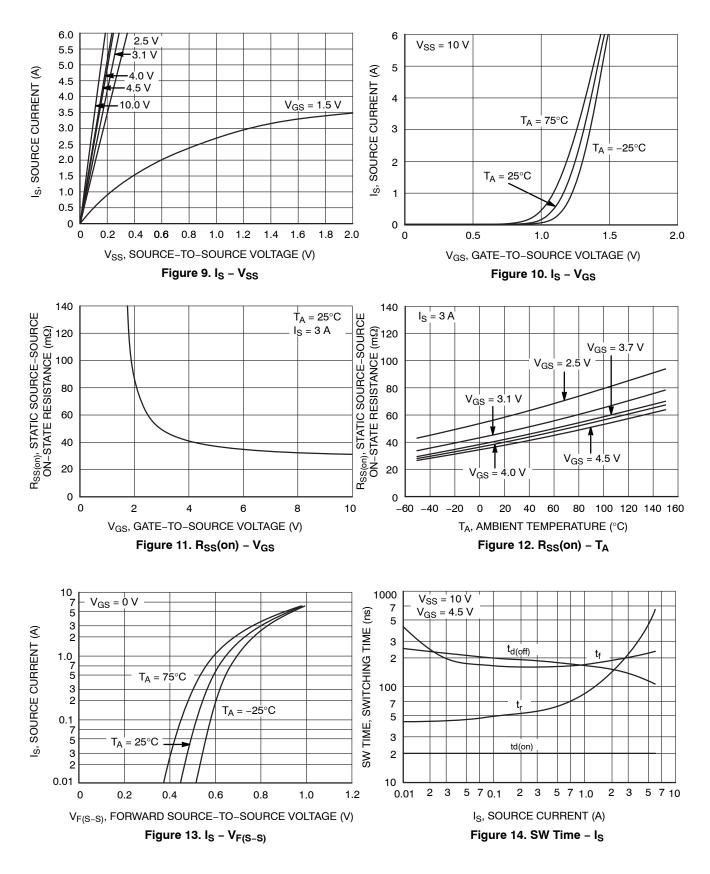
#### Test Circuit are Example of Measuring FET1 Side





## EFC4612R-S

#### **TYPICAL CHARACTERISTICS**



## EFC4612R-S

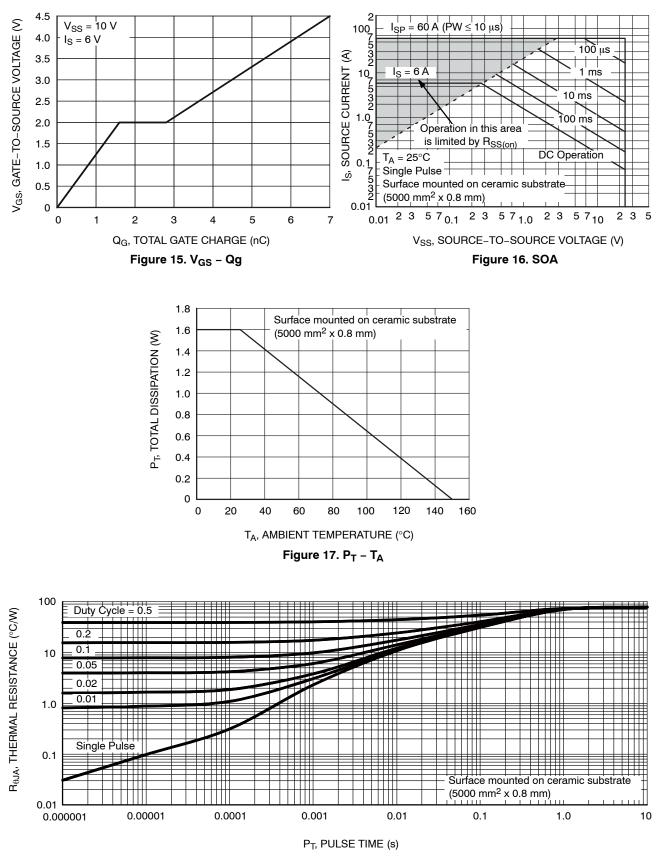


Figure 18.  $R_{\theta JA}$  – Pulse Time

# EFC4612R-S

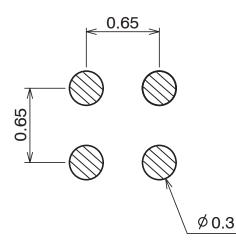
#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping $^{\dagger}$ (Qty / Packing)
EFC4612R-S-TR	FN	WLCSP4, 1.3 ×1.3 / EFCP1313–4CC–037 (Pb–Free and Halide Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

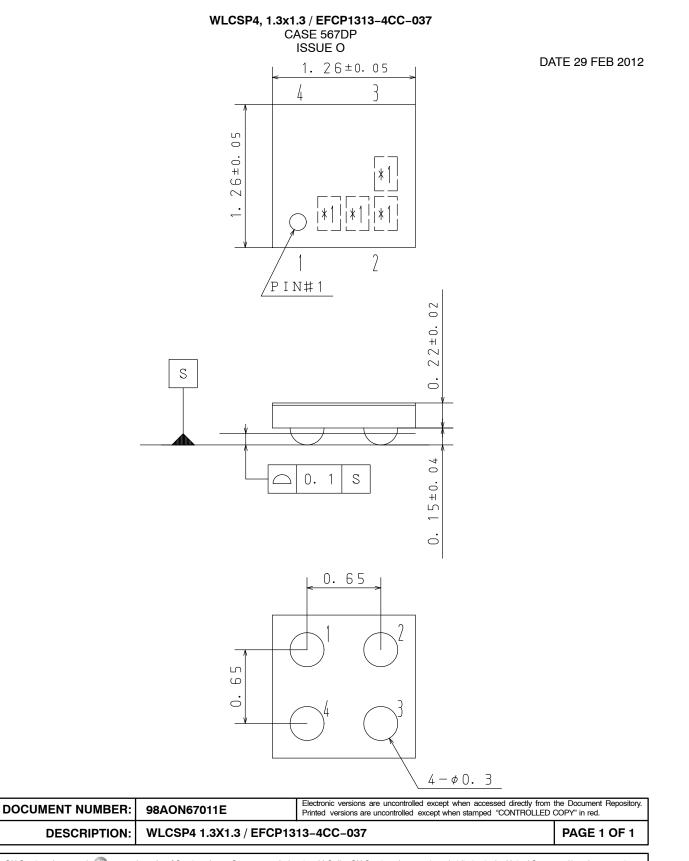
#### PACKAGE DIMENSION

(Unit: mm)









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